

Vishay Siliconix

RoHS

COMPLIANT HALOGEN

FREE

Available

Dual N-Channel 30 V (D-S) MOSFET

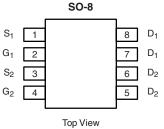
PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)		
30	0.022 at V _{GS} = 10 V	7.5		
	0.030 at V _{GS} = 4.5 V	6.5		

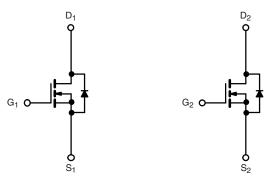
FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET •
- PWM Optimized •
- 100 % R_g Tested ٠
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

Symmetrical Buck-Boost DC/DC Converter





Ordering Information: Si4804BDY-T1-E3 (Lead (Pb)-free) Si4804BDY-T1-GE3 (Lead (Pb)-free and Halogen-free)

N-Channel MOSFET

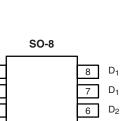
N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unle	ss otherwise r	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	30		V
Gate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current $(T_J = 150 \ ^{\circ}C)^a$	T _A = 25 °C	– I _D	7.5	5.7	
	T _A = 70 °C		6.0	4.6	
Pulsed Drain Current		I _{DM}	30		А
Continuous Source Current (Diode Conduction) ^a		۱ _S	1.7	0.9	
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	10 5		
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}			mJ
Maximum Power Dissipation ^a	T _A = 25 °C	– P _D	2.0	1.1	W
	T _A = 70 °C		1.3	0.7	vv
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
			Limits		
Parameter		Symbol	Тур.	Max.	Unit
Mauinum lunching to Amhienta	t ≤ 10 s	- R _{thJA} R _{thJF}	52	62.5	
Maximum Junction-to-Ambient ^a	Steady State		93	110	°C/W
Maximum Junction-to-Foot (Drain)	Steady State		35	40	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.



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Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	0.8		3.0	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zero Gate Voltage Drain Current		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ
	IDSS	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			15	
On-State Drain Current ^b	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	20			А
Drain-Source On-State Resistance ^b	Р	V _{GS} = 10 V, I _D = 7.5 A		0.017	0.022	0
	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 6.5 \text{ A}$		0.024	0.030	Ω
Forward Transconductance ^b	9 _{fs}	V _{DS} = 15 V, I _D = 7.5 A		19		S
Diode Forward Voltage ^b	V _{SD}	I _S = 1 A, V _{GS} = 0 V		0.75	1.2	V
Dynamic ^a				1		
Total Gate Charge	Qg			7	11	
Gate-Source Charge	Q _{gs}	V_{DS} = 15 V, V_{GS} = 4.5 V, I_D = 7.5 A		2.9		nC
Gate-Drain Charge	Q _{gd}			2.5		
Gate Resistance	R _g		0.5	1.5	2.6	Ω
Turn-On Delay Time	t _{d(on)}			9	15	
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		10	17	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong \text{1}$ A, V_GEN = 10 V, R_g = 6 Ω		19	30	ns
Fall Time	t _f			9	15	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 1.7 A, dl/dt = 100 A/μs		35	55	

Notes:

a. Guaranteed by design, not subject to production testing.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

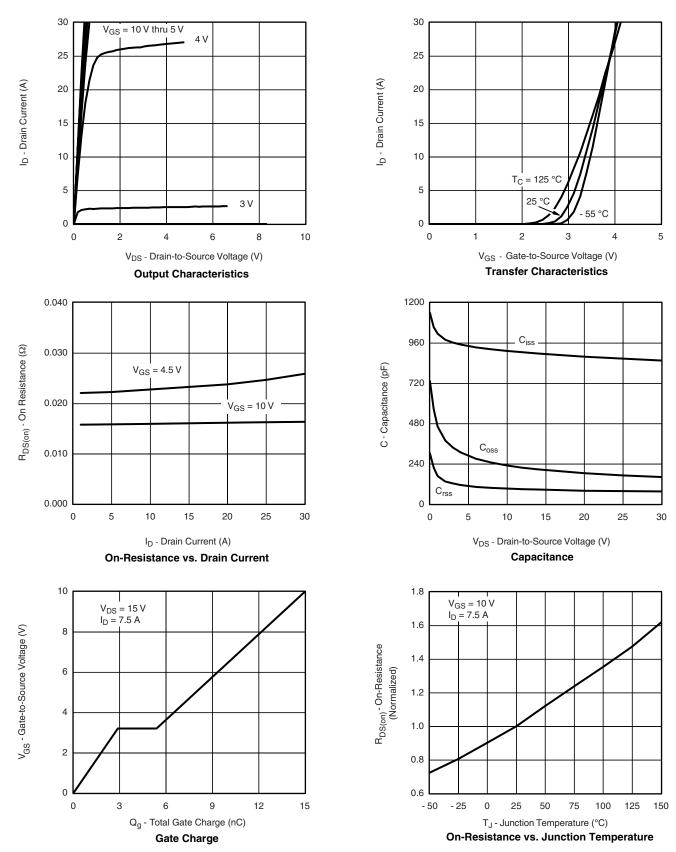
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



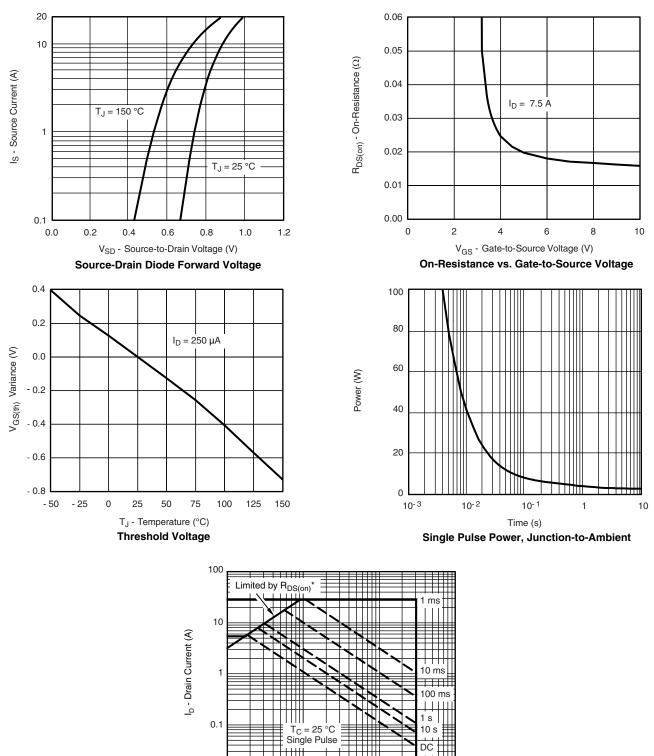
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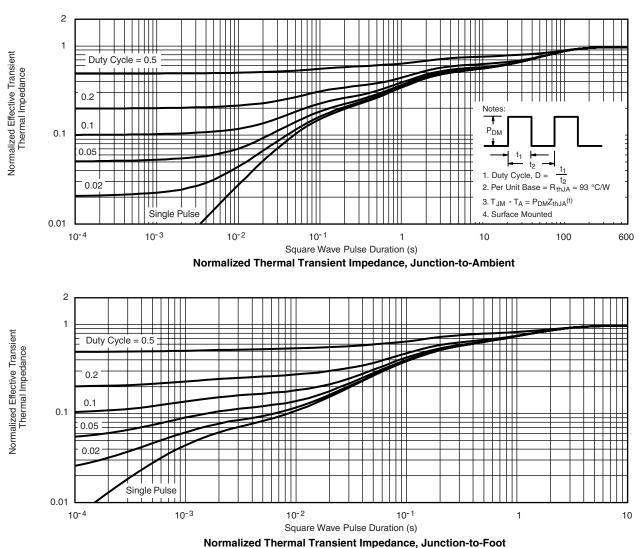
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 $\label{eq:VDS} \begin{array}{l} V_{DS} \text{ - Drain-to-Source Voltage (V)} \\ ^*V_{DS} \text{ > minimum } V_{GS} \text{ at which } R_{DS(on)} \text{ is specified} \\ \textbf{Safe Operating Area, Junction-to-Foot} \end{array}$

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

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